

To all our customers

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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

Cautions

Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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HD74HC132

Quad. 2-input NAND Schmitt Triggers

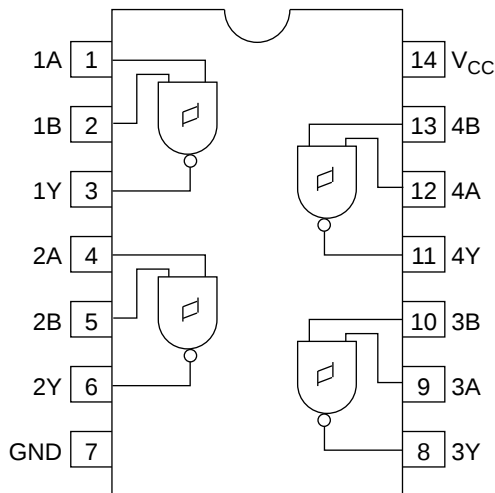


ADE-205-441 (Z)
1st. Edition
Sep. 2000

Features

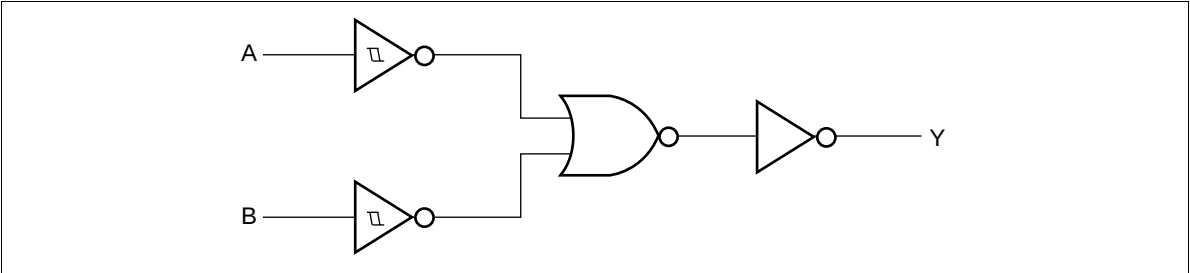
- High Speed Operation: $t_{pd} = 9.5 \text{ ns typ}$ ($C_L = 50 \text{ pF}$)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: $1 \mu\text{A max}$
- Low Quiescent Supply Current: $I_{CC}(\text{static}) = 1 \mu\text{A max}$ ($T_a = 25^\circ\text{C}$)

Pin Arrangement



(Top view)

Logic Diagram (1/4)



DC Characteristics

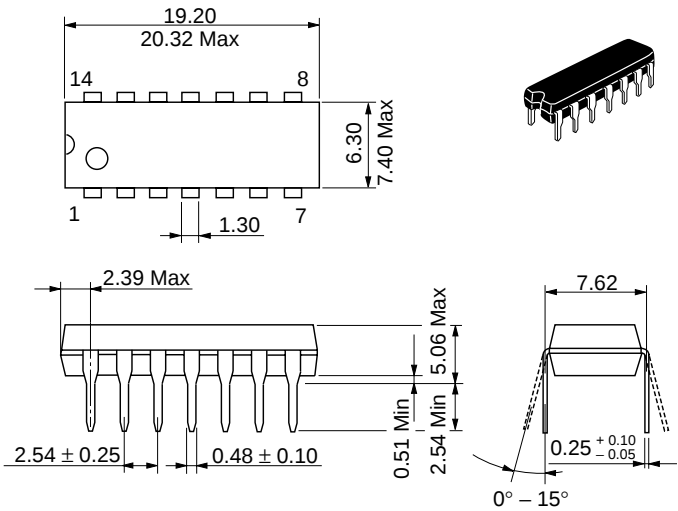
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Threshold voltage	V _{T+}	2.0	0.8	—	1.5	0.8	1.5	V		
		4.5	2.25	—	3.15	2.25	3.15			
		6.0	3.0	—	4.2	3.0	4.2			
	V _{T-}	2.0	0.2	—	1.0	0.2	1.0	V		
		4.5	0.9	—	2.25	0.9	2.25			
		6.0	1.2	—	3.0	1.2	3.0			
Hysteresis voltage	V _H	2.0	0.2	—	1.2	0.2	1.2	V		
		4.5	0.4	—	2.25	0.4	2.25			
		6.0	0.6	—	3.0	0.6	3.0			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V _{IH} or V _{IL} I _{OH} = -20 μA	
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I _{OH} = -4 mA
		6.0	5.68	—	—	5.63	—			I _{OH} = -5.2 mA
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V _{IH} or V _{IL} I _{OL} = 20 μA	
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I _{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I _{OL} = 5.2 mA
Input current	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0	—	—	1.0	—	10	μA	Vin = V _{CC} or GND, I _{out} = 0 μA	

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Item	Symbol	V _{CC} (V)	Ta = 25°C		Ta = −40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min		
Propagation delay time	t _{PLH}	2.0	—	—	100	—	125	ns
		4.5	—	8	20	—	25	
		6.0	—	—	17	—	21	
	t _{PHL}	2.0	—	—	100	—	125	ns
		4.5	—	11	20	—	25	
		6.0	—	—	17	—	21	
Output rise/fall time	t _{TLH}	2.0	—	—	75	—	95	ns
	t _{THL}	4.5	—	5	15	—	19	
		6.0	—	—	13	—	16	
Input capacitance	C _{in}	—	—	5	10	—	10	pF

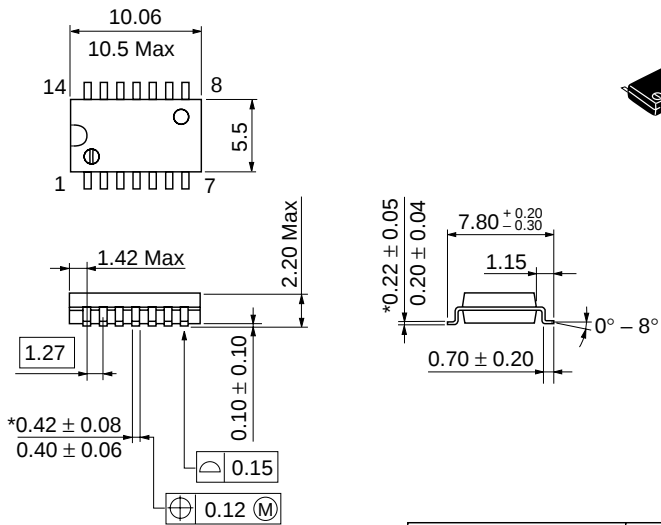
Package Dimensions

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.97 g

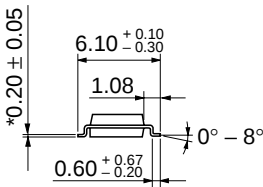
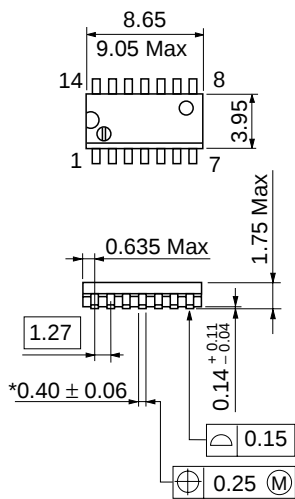
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.23 g

Unit: mm



*Pd plating

Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.13 g

Cautions

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